

RF Power Amplifier module

AP1100-10

This solid state power amplifier is designed for reliable, trouble-free service. It operates in a class A with a 26 V DC power supply. The amplifier is accommodated in aluminium housing.

Features :

- * 12 Watts saturated output power
- * 40 dB minimum gain
- * Electronic Attenuator in option
- * Overvoltage and reverse protection

Applications :

- * RF links
- * Test Bench
- * Field Test
- * Instrumentation

case B018-01

Specifications

Characteristics	Data	Units
Frequency range	1 MHz - 100 MHz	MHz
RF output power CW		
Typ.	11	W
Min	10	W
Class	A	
Power gain	40	dB
Flatness	+/-2 dB	dB
Input power for rated output power	0	dBm
Max. input power	10	dBm
In / Out impedances nom.	50	Ohms
Input VSWR	2 : 1	
Load VSWR for rated output power	up to 1.5 : 1	
VSWR mismatch	Infinite @ 10W	
Protection circuits	Load VSWR, over temperature	
Harmonics typ.	-16	dBc
Spurious typ.	-60	dBc
Modulation capability	100	%
Noise Figure typ.	10	dB
Intercept point 3 rd Order typ.		dBm
RF connectors	SMA female	
Cooling	by conduction	
Operating temperature Range	0 °C ... + 55	° C
Power Supply	26 DC +/- 5%	V
Dimensions (W x L x H)	case B018-01	mm
All data at room temperature + 22 °C, into 50 Ohms, subject to change without notice		